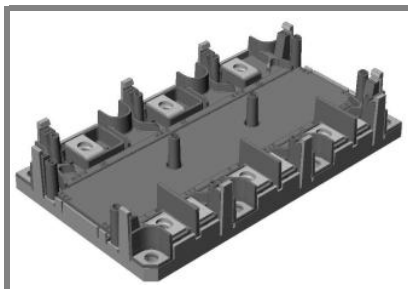


SKiM455GD12T4D1



SKiM[®] 5

Trench IGBT modules

SKiM455GD12T4D1

Preliminary Data

Features

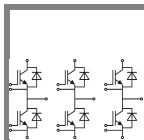
- IGBT 4 = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability

Typical Applications*

- High Reliability AC inverter drives
- UPS

Remarks

- Case temperature limited to $T_c = 125^\circ\text{C}$ max
- $T_{j,max}$ of the diode is limited to 150°C

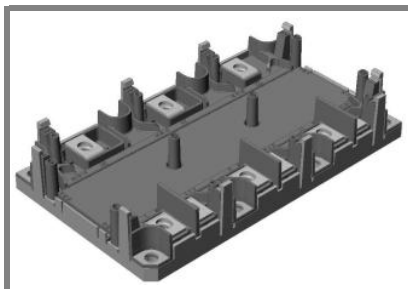


GD

Absolute Maximum Ratings		$T_c = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = ^\circ\text{C}$	1200		V
I_C	$T_j = 150^\circ\text{C}$	$T_{\text{heatsink}} = 25^\circ\text{C}$	400	A
		$T_{\text{heatsink}} = 70^\circ\text{C}$	305	A
I_{CRM}	$I_{CRM} = 3 \times I_{CNOM}$	1350		A
V_{GES}		± 20		V
t_{psc}	$V_{CC} = 800\text{ V}; V_{GE} \leq 15\text{ V}; T_j = 150^\circ\text{C}$ $V_{CES} < 1200\text{ V}$	10		μs
Inverse Diode				
I_F	$T_j = 150^\circ\text{C}$	$T_{\text{heatsink}} = 25^\circ\text{C}$	295	A
		$T_{\text{heatsink}} = 70^\circ\text{C}$	215	A
I_{FRM}	$I_{FRM} = 2 \times I_{FNOM}$	600		A
Module				
$I_{t(RMS)}$				A
T_{vj}		-40 ... +150		$^\circ\text{C}$
T_{stg}		-40 ... +125		$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500		V

Characteristics		$T_c = 25^\circ\text{C}$, unless otherwise specified				
Symbol	Conditions	min.	typ.	max.	Units	
IGBT						
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 18\text{ mA}$	5	5,8	6,5	V	
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}, T_j = 25^\circ\text{C}$			0,3	mA	
V_{CE0}		$T_j = 25^\circ\text{C}$	0,8	0,9	V	
		$T_j = 125^\circ\text{C}$	0,7	0,8	V	
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	2,2	2,4	$\text{m}\Omega$	
		$T_j = 125^\circ\text{C}$	3,1	3,3	$\text{m}\Omega$	
$V_{CE(sat)}$	$I_{Cnom} = 450\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}_{\text{chiplev.}}$	1,8	2	V	
		$T_j = 125^\circ\text{C}_{\text{chiplev.}}$	2,1	2,3	V	
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$			27,9	nF	
C_{oes}				1,7	nF	
C_{res}				1,5	nF	
Q_G	$V_{GE} = -8\text{V}/+15\text{V}$			2600	nC	
R_{Gint}	$T_j = 25^\circ\text{C}$			1,7	Ω	
$t_{d(on)}$	$R_{Gon} = 1\ \Omega$ $di/dt = 8200\text{ A}/\mu\text{s}$			265	ns	
t_r		$V_{CC} = 600\text{V}$ $I_C = 450\text{A}$			60	ns
E_{on}					34	mJ
$t_{d(off)}$	$R_{Goff} = 1\ \Omega$ $di/dt = 5300\text{ A}/\mu\text{s}$			470	ns	
t_f		$T_j = 125^\circ\text{C}$ $V_{GE} = \pm 15\text{V}$			65	ns
E_{off}					40	mJ
$R_{th(j-s)}$	per IGBT			0,14	K/W	

SKiM455GD12T4D1



SKiM® 5

Trench IGBT modules

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Preliminary Data

Features

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- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability

Typical Applications*

- High Reliability AC inverter drives
- UPS

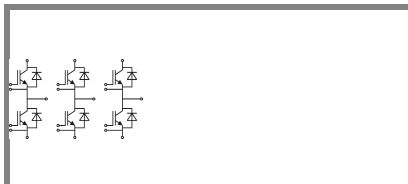
Remarks

- Case temperature limited to $T_c = 125^\circ\text{C}$ max
- $T_{j,max}$ of the diode is limited to 150°C

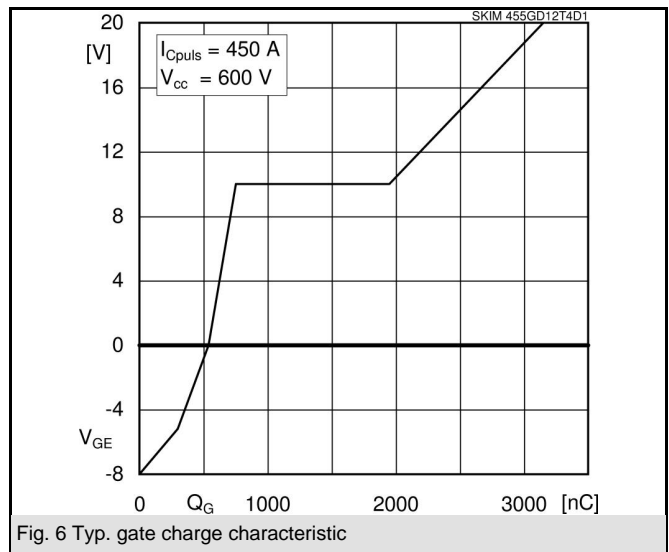
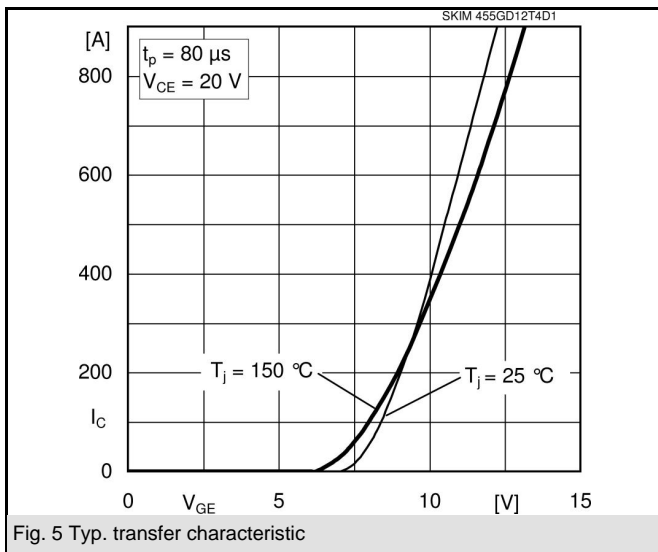
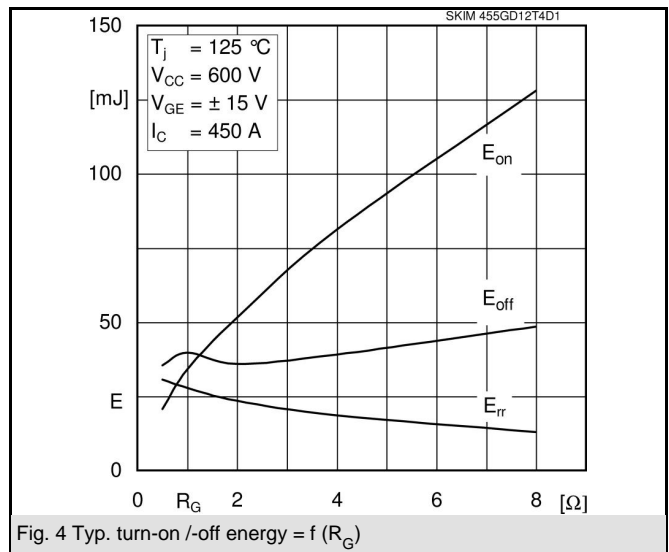
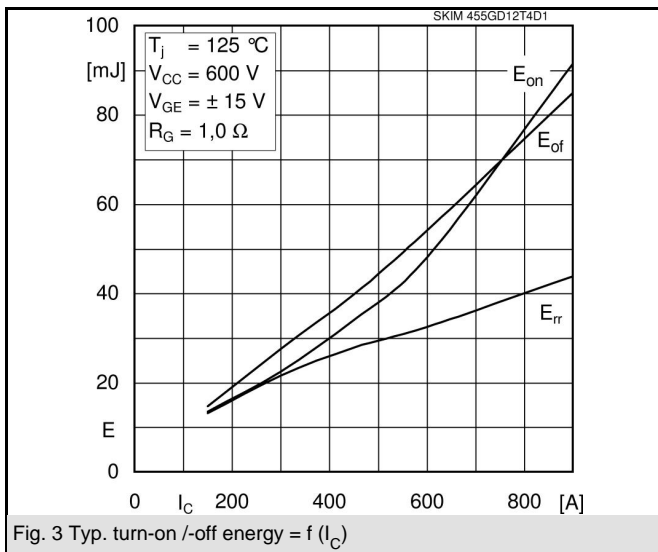
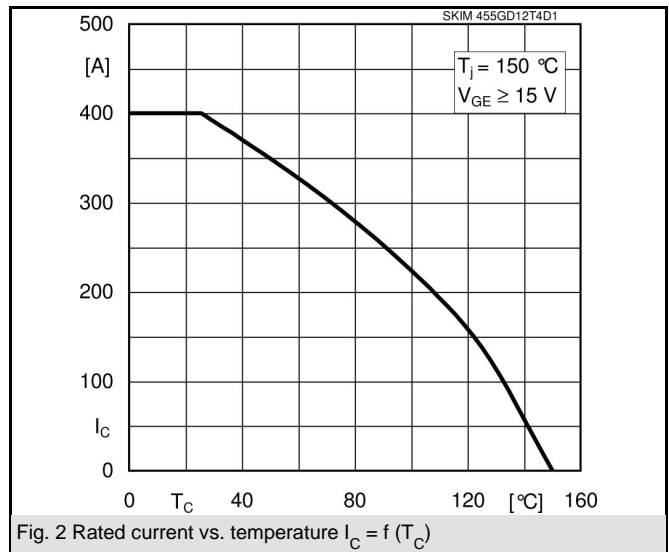
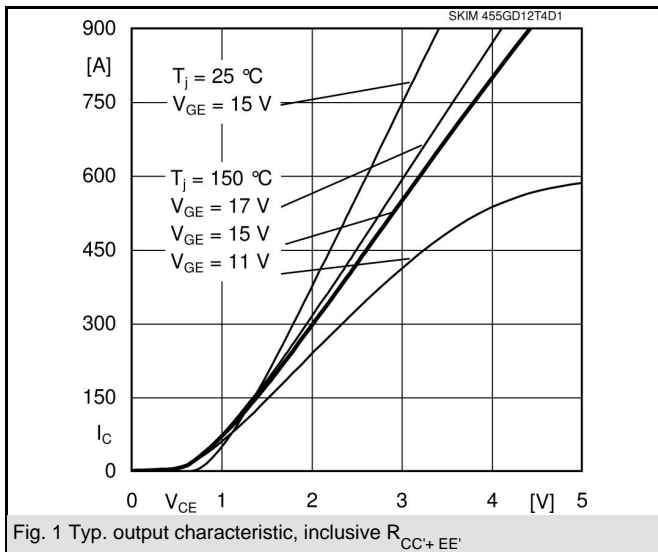
Characteristics					
Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 450\text{ A}; V_{GE} = 0\text{ V}$	$T_j = 25^\circ\text{C}_{chiplev.}$	2,3	2,8	V
		$T_j = 125^\circ\text{C}_{chiplev.}$	2,2	2,7	V
V_{F0}		$T_j = 25^\circ\text{C}$	1,2	1,6	V
		$T_j = 125^\circ\text{C}$	0,9	1,3	V
r_F		$T_j = 25^\circ\text{C}$	2,3	2,7	m Ω
		$T_j = 125^\circ\text{C}$	2,8	3,1	m Ω
I_{RRM}	$I_F = 450\text{ A}$	$T_j = 125^\circ\text{C}$	500		A
Q_{rr}	$di/dt = 9000\text{ A}/\mu\text{s}$		64,5		μC
E_{rr}	$V_{GE} = -15\text{ V}$		27,8		mJ
$R_{th(j-s)}$	per diode		0,19		K/W
Module					
L_{CE}				20	nH
R_{CC+EE}	res., terminal-chip	$T_{case} = 25^\circ\text{C}$	0,9		m Ω
		$T_{case} = 125^\circ\text{C}$	1,1		m Ω
M_s	to heat sink M5				Nm
M_t	to terminals M6		4	5	Nm
w				460	g
Temperature sensor					
R_{TS}	$T = 25 (100)^\circ\text{C}$		1 (1,67)		k Ω
Tolerance	$T = 25 (100)^\circ\text{C}$		3 (2)		%

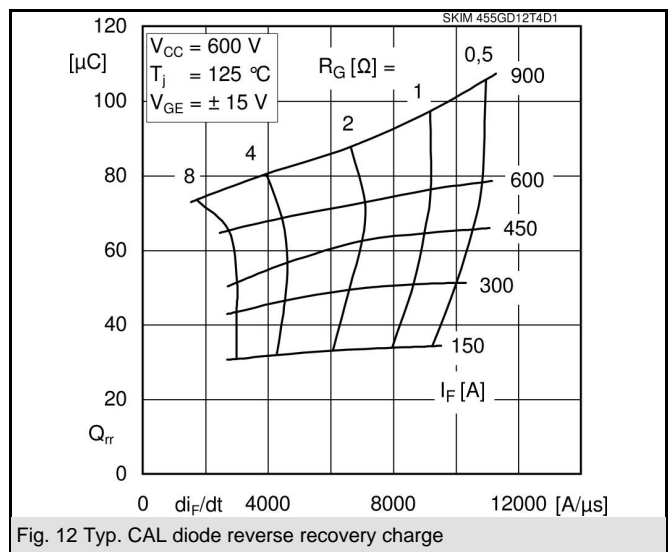
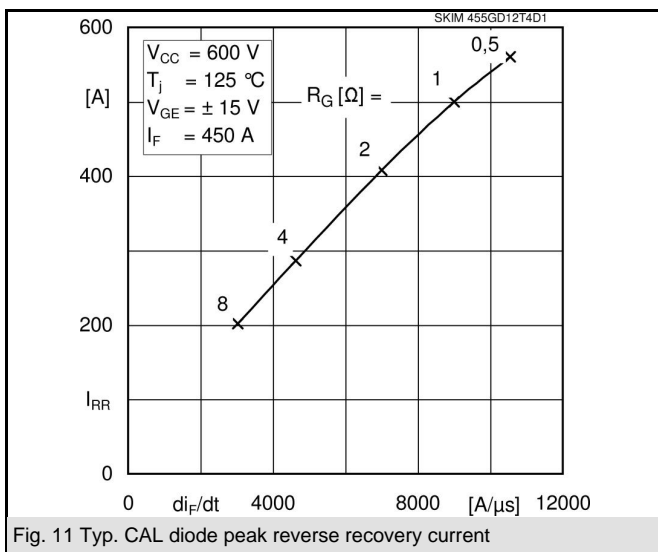
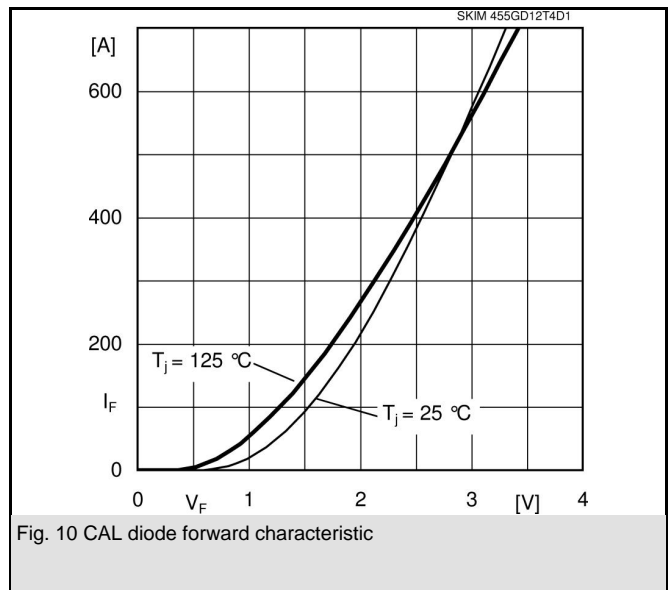
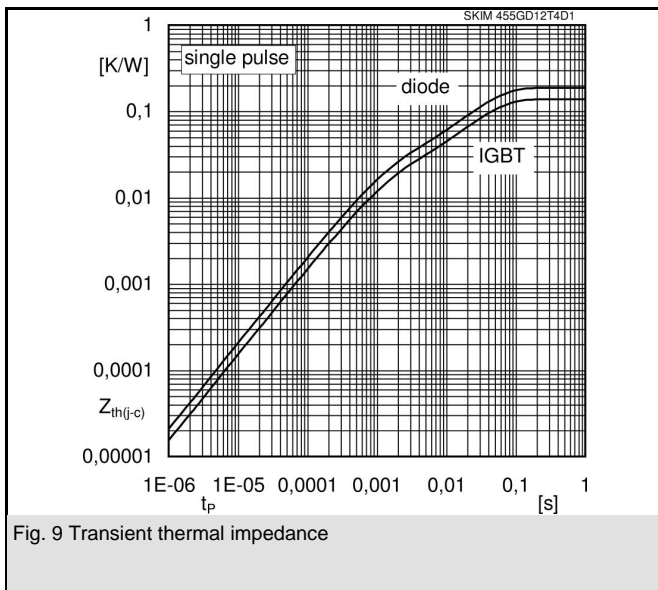
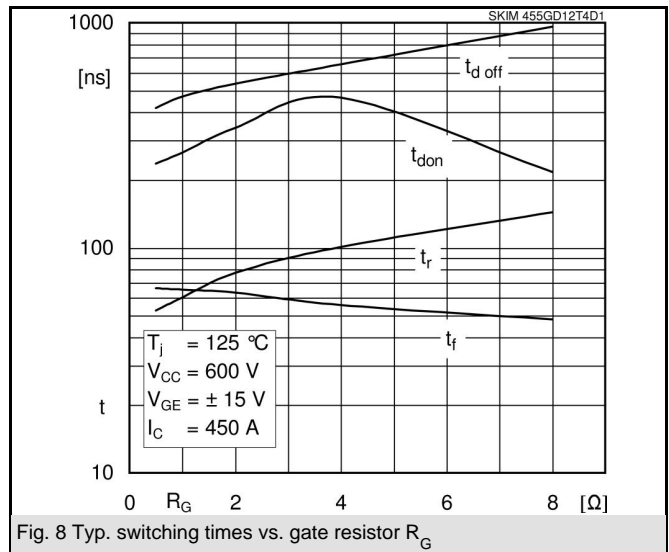
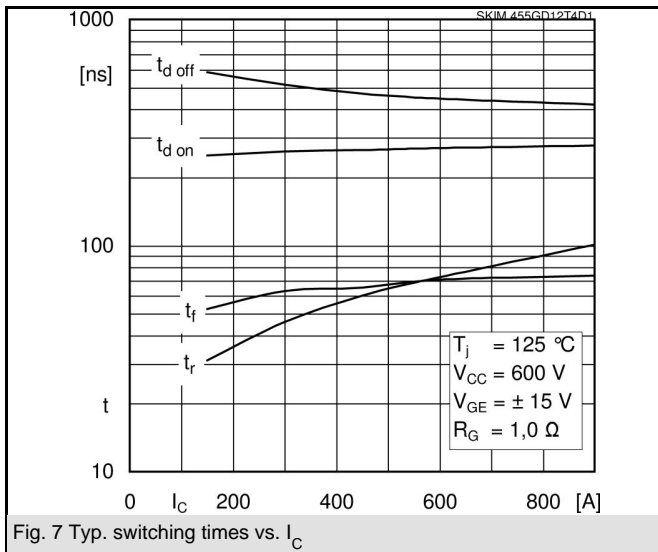
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



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UL recognized file

no. E 63 532

